

S2 S

S3 S

S0 S

S1 S

LED C

GND R

FOUT R

V_{DD} R

TSLM5xxx PACKAGE (TOP VIEW)

 $\bigcirc 1$

02

○ 3

 $\bigcirc 4$

○7

08

09

20 ()

19 ()

18 ()

17 ()

14 ()

13 ()

12 ()

 \bigcirc 10 11 \bigcirc

V_{DD} S

FOUT S

GND S

LED A

S1 R

S0 R

S3 R

S2 R

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•	Fully Integrated Sensor Includes LED and
	Photodetectors

- EOC230 Light-to-Frequency Converter Photodetectors Provide Outstanding Linearity
- Programming Pins Enable Very High Dynamic Range
- Operates Down to 3.3 V
- Reference Channel for Ambient Noise Cancellation
- Molded Plastic Lid With Optical Features Facilitates System Alignment
- Excellent for Calorimetric and Absorption and Refractive Index Measurements

Various LED Wavelengths Available

Description

Each of these chemical-optical sensor platforms consists of two EOC230 light-to-frequency converter detectors and a single high-efficiency light-emitting diode mounted on a glass/epoxy substrate and encapsulated in an injection-molded plastic lid with integral optical features.

Light from the LED is projected into waveguides (attached separately) by means of the molded optics in the center of the sensor lid. Light passing through the waveguides is directed onto the detectors by means of molded optics at each end of the sensor lid. The light impinging upon the detector surface will be affected by changes in the chemistry deposited on the sense waveguides. Neither the waveguides nor the chemistry on the sense waveguides is included with the sensor platform. Two EOC230 light-to-frequency converter detectors are incorporated to provide a sense channel and a reference channel.

The detector outputs are pulses, the frequencies of which correspond linearly with the amount of light impinging upon the detector surface. Sensitivity for each detector can be programmed for 1x, 10x, or 100x via logic signals applied to control pins S0 and S2 as shown in Table 1. Output frequency of each detector can be scaled to divide by 2, 10, or 100 via logic signals applied to control pins S2 and S3 (Table 1). The TSLM5xxx family of devices offers light-emitting diodes of various wavelengths to match specific chemistries and applications.

These chemical-optical sensor platforms are well suited for a wide variety of applications, including sensors for hydrocarbon, carbon monoxide, and oxygen detection, industrial hygiene, home safety, and chemistry development.

	S1	S0	SENSITIVITY	S3	S2	FOUT SCALING
	0	0 0 Power down		0	0	÷1
	0	1	1x	0	1	÷2
	1	0	10x	1	0	÷10
_	1	1	100x	1	1	÷100

Table 1. Control Pin Functions

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Terminal Functions

TERMI	NAL		
NAME	NO.	I/O	DESCRIPTION
S2 2	1	Ι	Sense channel
S3 S	2	Ι	Sense channel
S0 S	3	Ι	Sense channel
S1 S	4	Ι	Sense channel
	Х		
	Х		
LED C	7		LED cathode
GND R	8		Ground reference channel
FOUT R	9	0	Reference channel FOUT
$V_{DD} R$	10		Supply voltage reference channel
S2 R	11	- 1	Reference channel
S3 R	12	I	Reference channel
S0 R	13	- 1	Reference channel
S1 R	14	I	Reference channel
	Х		
	Х		
LED A	17		LED anode
GND S	18		Ground sense channel
FOUT S	19	0	Sense channel
V _{DD} S	20		Supply voltage sense channel

Absolute Maximum Ratings, $T_A = 25^{\circ}C$ (unless otherwise noted)[†]

Supply voltage range, V _{DD}	0 V to 6.5 V
Input voltage range, V _I , all inputs	\dots –0.3 V to V _{DD} + 0.3 V
Average LED current, dc	50 mA
Peak pulsed LED current, \leq 2-µs pulse width, \leq 10% duty cycle	500 mA
Operating temperature range, T _A	0°C to 70°C
Storage temperature range, T _{stg}	–20°C to 85°C
Lead temperature 1, 6 mm (1/16 inch), from seating plane	260°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Recommended Operating Conditions

		MIN	MAX	UNIT	
Supply voltage, V _{DD}			5.25	V	
	TSLM5585, TSLM5660, TSLM5880	5	20		
LED forward current, I _F	TSLM5470, TSLM5550, TSLM5620	20	50	mA	
Operating temperature	Case-to-ambient thermal resistance \leq 50°C/W	0	70	°C	

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Electrical Characteristics at V_{DD} = 5 V, T_A = 25°C (unless otherwise noted); test conditions represent worst-case values for the parameters under test

	PARAMETER		TEST CO	NDITIONS	MIN	TYP	MAX	UNI	
∕он	High-level output voltage		$V_{DD} = 5 V$, $I_F = 0 mA$		4.1		20		
V _{OL} Low-level output voltag		9	V _{DD} = 5 V,	I _F = 5 mA			0.38	V	
F(LED)	Forward voltage, LED		I _F = 5 mA				2		
(LED)	Reverse current, LED		V _R = 5 V				10	μA	
DH	Supply current, high-lev	el output					8	mA	
DL	Supply current, low-leve	el output					2	μΑ	
ł	High-level input current				-400		400		
	Low-level input current				-400		400	nA	
		TSLM5470	I _F = 20 mA			470			
		TSLM5550	I _F = 20 mA			555			
	Wavelength, LED	TSLM5585	I _F = 5 mA			585		nn	
	Wavelength, LED	TSLM5620	I _F = 20 mA			620			
		TSLM5660	I _F = 5 mA			660			
		TSLM5880	I _F = 5 mA			880			
	Output frequency	f _{Off(1)} , ÷ 1	S0, S1 = 1, V _{DD} = 5 V See Notes 1 and 3	S2, S3 = 0, I _F = 20 mA,	2		20		
		-On(1), * 1	V _{DD} = 5 V See Notes 1 and 4	I _F = 5 mA,	10		50		
		f _{OH(2)} , ÷ 2 f _{OH(10)} , ÷ 10	S0, S1, S2 = 1, $V_{DD} = 5 V$ See Notes 1 and 3	S3 = 0, I _F = 20 mA,	1		10		
			V _{DD} = 5 V See Notes 1 and 4	I _F = 5 mA,	5		25		
			S0, S1, S3 = 1, V_{DD} = 5 V See Notes 1 and 3	S2 = 0, I _F = 20 mA,	.2		2		
)			$V_{DD} = 5 V$ See Notes 1 and 4	I _F = 5 mA,	1		5	kH	
		f _{OH(100)} , ÷ 100	S0, S1, S2, S3 = 1, V _{DD} = 5 V	I _F = 20 mA, See Notes 1 and 3	0.02		0.2		
			¹ OH(100), ÷ 100	$V_{DD} = 5 V$ See Notes 1 and 4	I _F = 5 mA,	0.1		0.5	
		f _{OL(1)} , medium	S0, S2, S3 = 1, V _{DD} = 5 V	S1 = 1, I _F = 20 mA,	0.1		2		
			$V_{DD} = 5 V$ See Notes 1 and 4	I _F = 5 mA,	0.5		5		
		f _{OL(1)} , low	S1, S2, S3 = 0, V_{DD} = 5 V See Notes 1 and 3	S0 = 1, I _F = 20 mA,	0.01		0.2		
			$V_{DD} = 5 V$ See Notes 1 and 4	I _F = 5 mA,	0.05		0.5		
	Ratio		S0, S1 = 1, V _{DD} = 5 V See Notes 2 and 3	S2, S3 = 0, I _F = 20 mA,	0.25		4		
			V _{DD} = 5 V See Notes 2 and 4	I _F = 5 mA,					

NOTES: 1. Applies both to sense and to reference channels

2. Variance between sense and reference channels expressed as a ratio

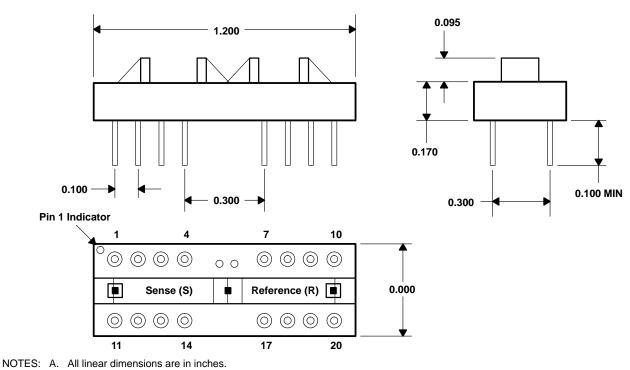
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Applies to TSLM5585, TSLM5660 and TSLM5880 only

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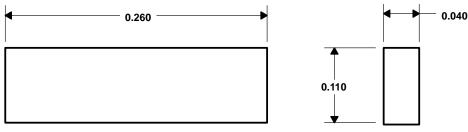
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MECHANICAL INFORMATION

B. This drawing is subject to change without notice.





NOTES: A. All linear dimensions are in inches.

B. This drawing is subject to change without notice.

Figure 2. Typical Waveguide Dimensions



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